## NSN 5961-01-580-6135

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-580-6135 **Inclosure Material:** Glass **Overall Length:** Between 0.100 inches and 0.170 inches **Terminal Length:** Between 0.975 inches and 1.500 inches **Overall Diameter:** Between 0.045 inches and 0.076 inches **End Application:** Ca70608-001 (19156), receiver-transmitter **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 working peak reverse voltage, peak total value **Power Rating Per Characteristic:** 0.3 watts forward power dissipation, peak, total value **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Product Name:** (dwg title) semiconductor device, diode, silicon, switching, type 1n5719 **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No Fiig: A110a0